

Industry Smallest and Low Profile 3W 0.6A DC/DC Boost Converter with High Output Density Power



FEATURES

- Fully integrated DC/DC converter
- High efficiency over large load range
- 2MHz switching frequency
- 100% duty cycle
- Power density - more than 100W/inch³
- 1uA shutdown current
- 2.5V to 6V input range (1Li+ and 3-cell NiCd or NiMH cells)
- 3.3V to 6V output voltage
- Programmable PWM/PSM controls
- Low output ripple
- BGA/LGA construction
- Temperature range: - 40°C to + 85°C
- No external components needed
- Output power 3W
- Maximum current 600mA
- Low profile

The DC/DC converter provides fully integrated synchronous boost converter solution for the latest one-cell lithium ion cellular phones. Its input voltage is between 2.5V to 6V, capable of delivering up to 600mA of output current at 3.3V to 6V. The DC/DC converter combines the 2MHz-switching controller with fully integrated passive components needed to deliver the smallest and most efficient converter available today. The high switching frequency minimizes the output capacitance with peak to peak output ripple as low as 20mV. The DC/DC converter delivers efficiency up to 95%. The programmable pulse-skipping mode (PSM) maintains this high efficiency even during the standby and idle modes to increase overall battery life and talktime. In order to extract the last ounce of power from the battery, the DC/DC converter is designed with 100% duty cycle control for this mode. This function enables the DC/DC converter to operate like a saturated linear regulator delivering the highest potential

output voltage for longer talk time. The DC/DC converter is available in 20-ports BGA package. In order to satisfy the stringent ambient temperature requirements, the DC/DC converter is designed to handle the industrial temperature range of - 40°C to + 85°C.

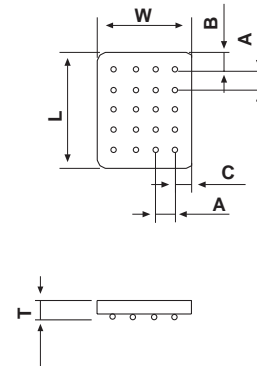
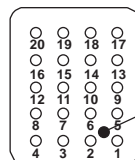
APPLICATION

- Cordless phones, PDAs and others
- Supply voltage source for low voltage chip sets
- Portable computers
- Battery back-up supplies
- Cameras
- Routers
- Fiber optics
- LANS
- Image processing

ORDERING INFORMATION

	FX	5545	G202	□ □ □	□ □
FUNCTION					
SIZE					
CIRCUIT IDENTIFIER					
OUTPUT VOLTAGE-Example: 5.0V should be written as 5V0 as the V indicates the decimal point, or ADJ for adjustable version - self selectable output voltage.					
PACKAGING-B1 = 10pcs in bulk; B5 = 50pcs in bulk; T1 = 13" reel; T2 = 7" reel.					

DIMENSIONS in inches [millimeters]	
L	0.58 ± 0.01 [14.7 ± 0.25]
W	0.48 ± 0.01 [12.2 ± 0.25]
A	0.1 ± 0.01 [2.54 ± 0.25]
B	0.09 ± 0.01 [2.29 ± 0.25]
C	0.09 ± 0.01 [2.27 ± 0.25]
T	0.12 max [3 max]

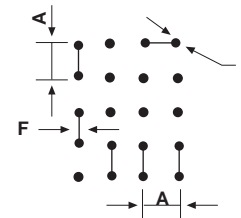

BOTTOM SIDE


Marked on Upper Side

*Note: Pin Description application note is available on page 32.

PIN CONFIGURATION*	
PIN	CONNECTION
1	N/C
2, 6	\overline{SD}
3, 7	PWM/PSM
4, 8	SYNC
5, 9	Vout
10 - 12	N/C
13, 17	GND
14 - 16	N/C
18	N/C
19, 20	Vin

RECOMMENDED PAD PATTERN in inches [millimeters]		
A	D	F
0.1 ± 0.01 [2.54 ± 0.25]	0.03 ± 0.001 [0.8 ± 0.02]	0.02 ± 0.001 [0.5 ± 0.02]


TAPE AND REEL

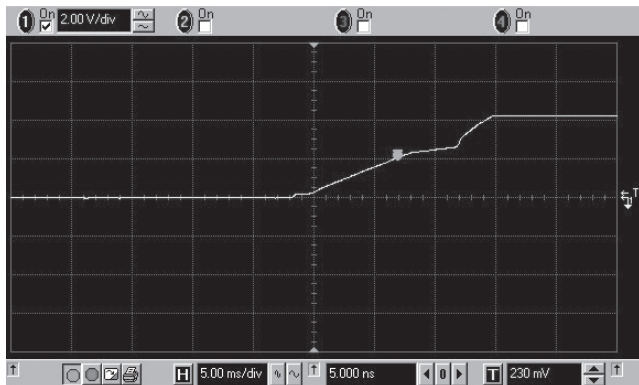
See Tape and Reel Information - Type B



STANDARD ELECTRICAL SPECIFICATIONS					
PARAMETER	UNIT	CONDITION	MIN	TYP	MAX
Input					
Voltage Range	V_{DC}		2.5		6
Quiescent Current	A	PSM mode		200	
Soft Start Time	ms	T_{SS}		17	
SD, PWM/PSM, SYNC					
Logic High	V	V_H	2.4		
Logic Low	V	V_L			0.8
Normal Mode	A	I_{DD}			750
PSM Mode	A	I_{DD}			250
Shutdown Mode	A	I_{DD}			1
Shutdown Time	ms	T_{SS}		19	
Insulation					
Test Voltage	V_{AC}	60Hz 60sec	750		
Resistance	Ω	$V_{ISO} = 500V_{DC}$	1×10^{11}		
Leakage Current	nA	$V_{ISO} = 500V_{DC}$			5
Output					
Power	W			3	
Voltage	V_{DC}			3.3 to 6	
Voltage Tolerance	%	at 25°C Ambient Temperature	- 3		3
Temp. Coefficient	%/°C				0.03
Ripple and Noise	mVpp	DC to 20MHz		45	
General					
Package Weight	gr.				1.5
Oscillator					
Frequency	MHz			2	
SYNC Range		F_{SYNC}/F_{OSC}	1.2		1.5
Temperature					
Operation	°C		- 40		+ 85
Storage	°C		- 55		+ 125
Operating Junction Temp.	°C	T_j		150	
Thermal Impedance	°C/ W_D^*	θ_{JA}		82	

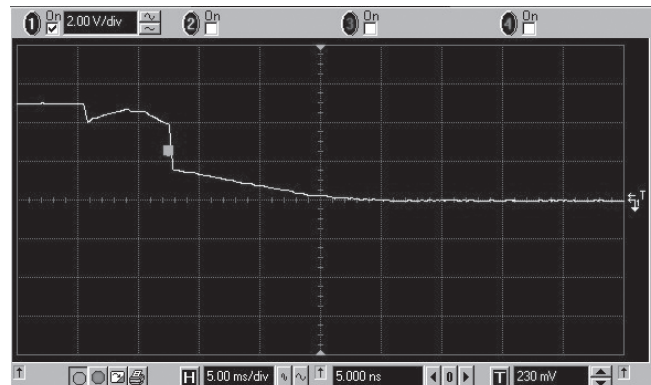
Note: W_D = Power Dissipated

Rise Time

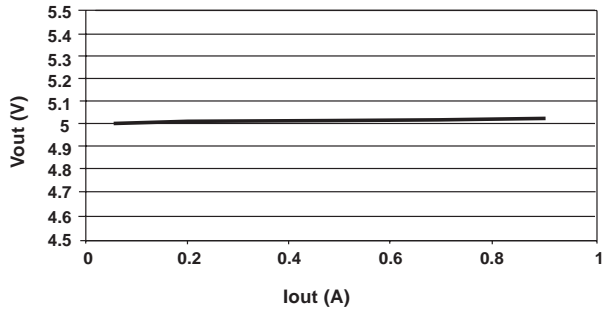
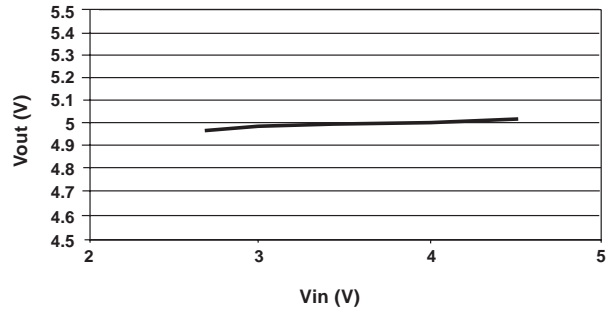
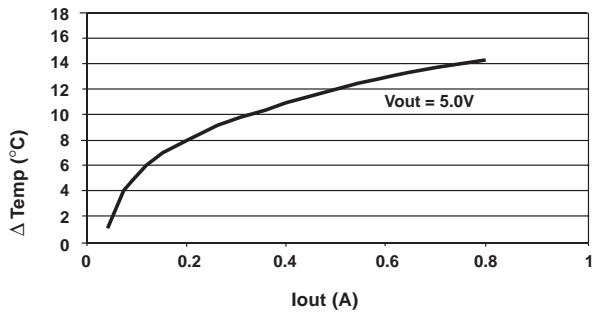
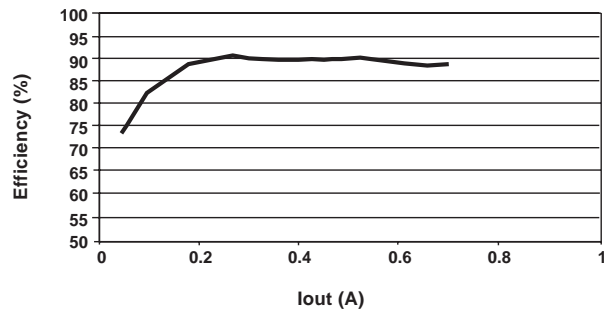
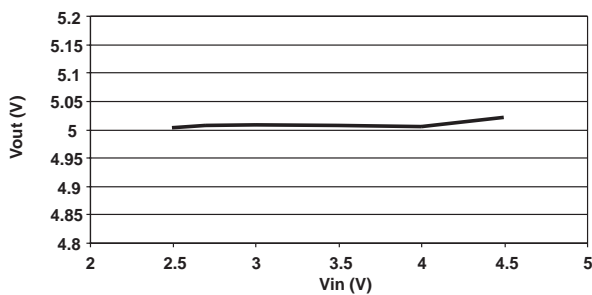
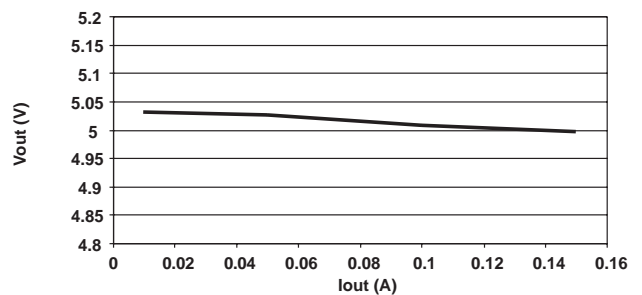


Rise Time (PWM mode): $V_{in} = 3.5V$; $V_{out} = 5V$; $I_{out} = 0.7A$

Fall Time



Fall Time (PWM mode): $V_{in} = 3.5V$; $V_{out} = 5V$; $I_{out} = 0.7A$

Vout Vs. Iout
Vin = 3.6V

Vout Vs. Vin
Iout = 500mA

Δ Temp Vs. Iout
Above 25°C Ambient Temperature

Efficiency Vs. Iout
Vin = 3.6V; Vout = 5.0V

Vout Vs. Vin (PSM mode)
Iout = 0.1A

Vout Vs. Iout (PSM mode)
Vin = 3V

Efficiency Vs. Iout (PSM mode)
